International Rectifier

MUR1520 MURB1520 MURB1520-1

Ultrafast Rectifier

Features

- · Ultrafast Recovery Time
- · Low Forward Voltage Drop
- · Low Leakage Current
- · 175°C Operating Junction Temperature

 t_{rr} = 35ns $I_{F(AV)}$ = 15Amp V_R = 200V

Description/ Applications

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time.

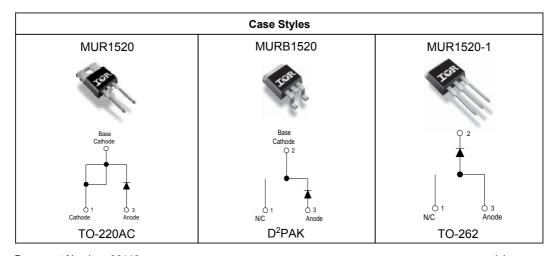
The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

	Parameters	Max	Units
V_{RRM}	Peak Repetitive Peak Reverse Voltage	200	V
I _{F(AV)}	Average Rectified Forward Current	15	A
	Total Device, (Rated V _R), T _C = 150°C		
I _{FSM}	Non Repetitive Peak Surge Current	200	
I _{FM}	Peak Repetitive Forward Current	30	
(Rated V	R, Square wave, 20 KHz), T _C = 150°C		
T _J , T _{STG}	Operating Junction and Storage Temperatures	-65 to 175	°C



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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Conditions
V _{BR} , V _r	Breakdown Voltage, Blocking Voltage	200	-	-	٧	Ι _R = 100μΑ
V _F	Forward Voltage	-	-	1.05	V	I _F = 15A
		-	-	0.85	V	I _F = 15A, T _J = 150°C
I _R	Reverse Leakage Current	-	-	10	μΑ	V _R = V _R Rated
		-	-	500	μA	$T_J = 150$ °C, $V_R = V_R$ Rated
Ст	Junction Capacitance	-	55	-	pF	V _R = 200V
Ls	Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

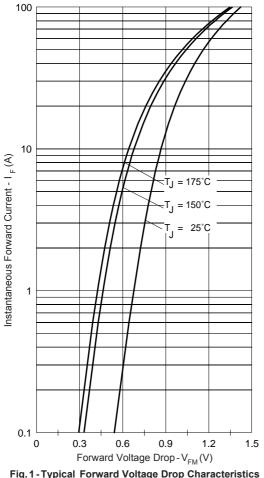
Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Condition	s
t _{rr}	Reverse Recovery Time	-	-	35	ns	$I_F = 1.0A$, $di_F/dt = 50A/\mu s$, $V_R = 30V$	
		-	22	-		T _J = 25°C	I _F = 15A
		-	39	-		T _J = 125°C	V _R = 160V
I _{RRM}	Peak Recovery Current	-	1.6	-	Α	$T_J = 25^{\circ}C$	$di_F/dt = 200A/\mu s$
		-	4.1	-		T _J = 125°C	
Q _{rr}	Reverse Recovery Charge	-	19	-	nC	T _J = 25°C	
		-	90	-		T _J = 125°C	

Thermal - Mechanical Characteristics

	Parameters	Min	Тур	Max	Units
TJ	Max. Junction Temperature Range	- 65	-	175	°C
T _{Stg}	Max. Storage Temperature Range	- 65	-	175	
R _{thJC}	Thermal Resistance, Junction to Case	-	-	1.5	°C/W
R _{thJA}	Thermal Resistance, Junction to Ambient	-	-	50	
R _{thCS} ①	Thermal Resistance, Case to Heatsink	-	0.5	-	
Wt	Weight	-	2.0	-	g
		-	0.07	-	(oz)
	Mounting Torque	6.0	-	12	Kg-cm
		5.0	-	10	lbf.in

 $^{{\}small \textcircled{1}} \quad \text{Mounting Surface, Flat, Smooth and Greased}$



1000 = 175°C Reverse Current - I R (µA) 100 150°C 125°C 10 100°C 0.1 25°C 0.01 0 250 50 100 Reverse Voltage - $V_R(V)$

Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

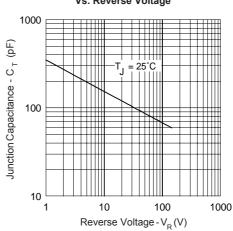
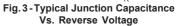


Fig. 1-Typical Forward Voltage Drop Characteristics



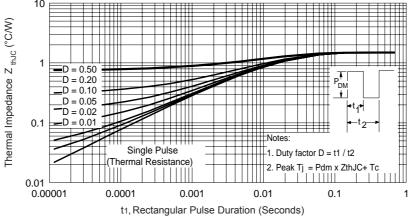


Fig. 4-Max. Thermal Impedance \mathbf{Z}_{thJC} Characteristics

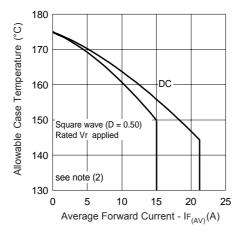


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

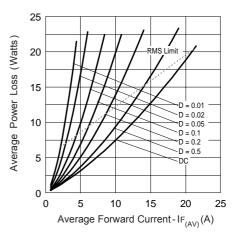


Fig. 6-Forward Power Loss Characteristics

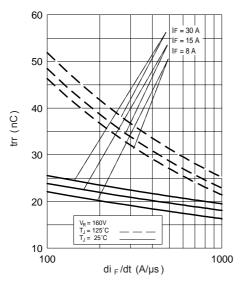


Fig. 7 - Typical Reverse Recovery vs. di F/dt

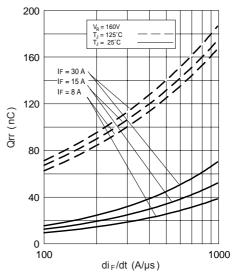


Fig. 8 - Typical Stored Charge vs. di F/dt

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} x V_{FM} @ (I_{F(AV)} / D) \text{ (see Fig. 6)};$ Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_{R} (1 - D)$; $I_{R} @ V_{R1}$ = rated V_{R}

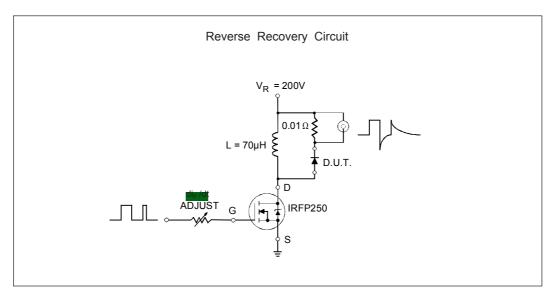


Fig. 9- Reverse Recovery Parameter Test Circuit

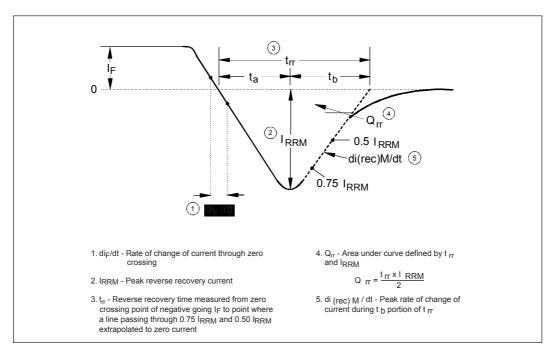
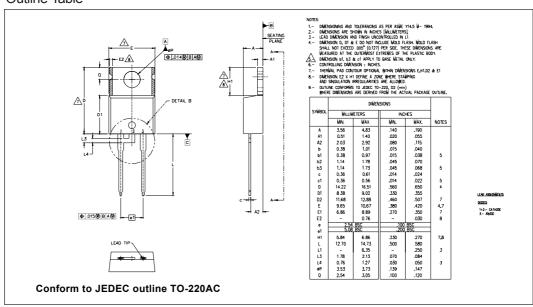
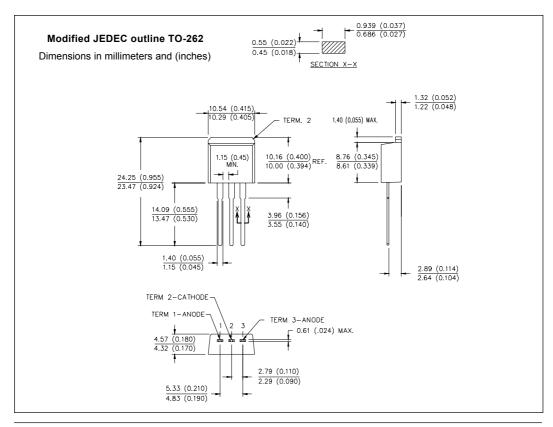


Fig. 10 - Reverse Recovery Waveform and Definitions

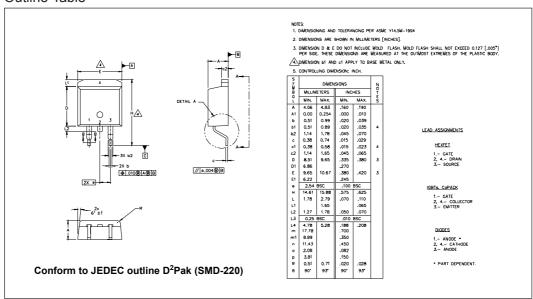
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Outline Table

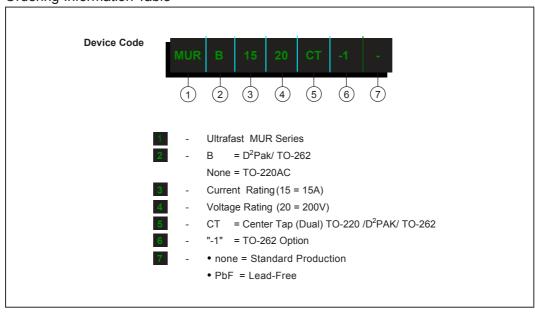




Outline Table



Ordering Information Table



Bulletin PD-20727 rev. E 02/06

* SPICE Model Diode * *SUBCKT MUR1520 ANO CAT D1 ANO 1 CAT *Define diode model

.MODEL DMOD D Is=16.9E-09 N=1.332 Rs=4.439E-03 Ikf=.232 Xti=2 Eg=1.11 Cjo=700.3E-09 M=.3715 Vj=.1784 Fc=.5 Isr=1.389E-09 Nr=3.002 Bv=270 Ibv=95.79E-6 Tt=10.49E-9)

.ENDS MUR1520

Thermal Model Subcircuit .SUBCKT MUR1520 5 1

CTHERM1	5	4	2.23E+01
CTHERM2	4	3	1.23E+02
CTHERM3	3	2	3.35E+02
CTHERM4	2	1	4.75E+02
RTHERM1	5	4	7.55E-01
RTHERM2	4	3	5.90E-02
RTHERM1	3	2	1.01E-01
RTHERM1	2	1	5.43E-02

.ENDS MUR1520

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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02/06



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Document Number: 99901 www.vishay.com
Revision: 12-Mar-07 1